

Day : Thursday
Date: 8/10/2006

Time: 05:40:45

PALM INTRANET

Inventor Name Search Result

Your Search was:

Last Name = SAKURADA

First Name = MASAHIRO

Application#	Patent#	Status	Date Filed	Title	Inventor Name
<u>08498894</u>	<u>5609682</u>	150	07/06/1995	A METHOD FOR THE PREPARATION OF SILICON SINGLE CRYSTAL	SAKURADA, MASAHIRO
<u>08565100</u>	<u>5667584</u>	150	11/30/1995	METHOD FOR THE PREPARATION OF A SINGLE CRYSTAL OF SILICON WITH DECREASED CRYSTAL DEFECTS	SAKURADA, MASAHIRO
<u>08655810</u>	<u>5817171</u>	150	05/31/1996	APPARATUS AND METHOD FOR PRODUCING SINGLE CRYSTAL USING CZOCHRALSKI TECHNIQUE	SAKURADA, MASAHIRO
<u>08660198</u>	<u>5728211</u>	250	06/03/1996	SILICON SINGLE CRYSTAL WITH LOW DEFECT DENSITY AND METHOD OF PRODUCING SAME	SAKURADA, MASAHIRO
<u>08666654</u>	<u>5704973</u>	150	06/18/1996	AN APPARATUS AND METHOD FOR THE UNIFORM DISTRIBUTION OF CRYSTAL DEFECTS UPON A SILICON SINGLE CRYSTAL	SAKURADA, MASAHIRO
<u>08768282</u>	<u>5730800</u>	150	12/17/1996	FUSED SILICA GLASS CRUCIBLE	SAKURADA, MASAHIRO
<u>08798472</u>	<u>5948163</u>	250	02/10/1997	APPARATUS FOR MANUFACTURING CRYSTALS ACCORDING TO THE CZOCHRALSKI METHOD, AND CRYSTALS MANUFACTURED BY THE MANUFACTURING METHOD	SAKURADA, MASAHIRO
<u>09090400</u>	<u>5938842</u>	150	06/04/1998	METHOD FOR PRODUCING A SINGLE CRYSTAL USING CZOCHRALSKI TECHNIQUE	SAKURADA, MASAHIRO

<u>09125339</u>	<u>6071337</u>	150	08/13/1998	APPARATUS AND METHOD FOR PRODUCING CRYSTALS BY THE CZOCHRALSKI METHOD AND CRYSTALS PRODUCED BY THIS METHOD	SAKURADA, MASAHIRO
<u>09232561</u>	<u>6174364</u>	150	01/15/1999	METHOD FOR PRODUCING SILICON MONOCRYSTAL AND SILICON MONOCRYSTAL WAFER	SAKURADA, MASAHIRO
<u>09328278</u>	<u>6190452</u>	150	06/08/1999	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR PRODUCING IT	SAKURADA, MASAHIRO
<u>09646713</u>	<u>6565822</u>	150	09/21/2000	EPITAXIAL SILICON WAFER, METHOD FOR PRODUCING THE SAME AND SUBSTRATE FOR EPITAXIAL SILICON WAFER	SAKURADA, MASAHIRO
<u>09727275</u>	<u>6482260</u>	150	11/30/2000	SILICON SINGLE CRYSTAL WAFER AND A METHOD FOR PRODUCING IT	SAKURADA, MASAHIRO
<u>10204935</u>	<u>6913646</u>	150	08/27/2002	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR PRODUCING SILICON SINGLE CRYSTAL	SAKURADA, MASAHIRO
<u>10312921</u>	<u>6893499</u>	150	12/26/2002	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR MANUFACTURING THE SAME	SAKURADA, MASAHIRO
<u>10500580</u>	Not Issued	93	07/01/2004	AN SOI WAFER AND A METHOD FOR PRODUCING AN SOI WAFER	SAKURADA, MASAHIRO
<u>10512470</u>	Not Issued	30	10/26/2004	A SILICON SINGLE CRYSTAL WAFER, AN EPITAXIAL WAFER AND A METHOD FOR PRODUCING A SILICON SINGLE CRYSTAL	SAKURADA, MASAHIRO
<u>10516347</u>	Not Issued <i>Applicants Inventor</i>	30	11/30/2004	GRAPHITE HEATER FOR PRODUCING SINGLE CRYSTAL, APPARATUS FOR PRODUCING SINGLE CRYSTAL, AND METHOD FOR PRODUCING SINGLE CRYSTAL	SAKURADA, MASAHIRO
<u>10530557</u>	Not Issued	20	04/07/2005	Annealed wafer and method for manufacturing the same	SAKURADA, MASAHIRO

<u>10538878</u>	Not Issued	41	06/14/2005	Method of producing p-doped silicon single crystal and p-doped n-type silicon single crystal wafer	SAKURADA, MASAHIRO
<u>10542376</u>	Not Issued	30	07/14/2005	AN SOI WAFER AND A METHOD FOR PRODUCING THE SAME	SAKURADA, MASAHIRO
<u>10546693</u>	Not Issued	25	08/22/2005	An soi wafer and a method for producing the same	SAKURADA, MASAHIRO
<u>10560581</u>	Not Issued	19	01/01/0001	Method for producing a single crystal and a single crystal	SAKURADA, MASAHIRO
<u>10561205</u>	Not Issued	25	02/03/2006	Process for producing single crystal and single crystal	SAKURADA, MASAHIRO
<u>10561865</u>	Not Issued	41	02/20/2006	Method for producing single crystal and single crystal	SAKURADA, MASAHIRO

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Day : Thursday
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Time: 05:43:19

Inventor Name Search Result

Your Search was:

Last Name = FUSEGAWA

First Name = IZUMI

Application#	Patent#	Status	Date Filed	Title	Inventor Name
<u>06941624</u>	Not Issued	161	12/11/1986	METHOD AND APPARATUS FOR CZOCHRALSKI SINGLE CRYSTAL GROWING	FUSEGAWA, IZUMI
<u>07242414</u>	4956153	250	09/09/1988	APPARATUS FOR CZOCHRALSKI SINGLE CRYSTAL GROWING	FUSEGAWA, IZUMI
<u>07496750</u>	5110404	150	03/21/1990	METHOD FOR HEAT PROCESSING OF SILICON	FUSEGAWA, IZUMI
<u>07703750</u>	Not Issued	166	05/21/1991	METHOD FOR PULLING UP SEMICONDUCTOR SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>07713848</u>	5306387	150	06/12/1991	METHOD FOR PULLING UP SEMICONDUCTOR SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>07729026</u>	Not Issued	161	07/12/1991	METHOD FOR PULLING SEMICONDUCTOR SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>07796385</u>	5688319	150	11/22/1991	METHOD FOR TESTING ELECTRICAL PROPERTIES OF SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>07850506</u>	5262338	250	03/13/1992	METHOD FOR FABRICATION OF SEMICONDUCTOR DEVICE	FUSEGAWA, IZUMI
<u>07850915</u>	Not Issued	166	03/13/1992	HEAT TREATMENT OF SI SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>07850916</u>	5386796	150	03/13/1992	METHOD FOR TESTING QUALITY OF SILICON WAFER	FUSEGAWA, IZUMI
<u>07852612</u>	5248378	150	03/17/1992	METHOD AND APPARATUS FOR PRODUCING SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>07953918</u>	5359959	150	09/30/1992	METHOD FOR PULLING UP	FUSEGAWA, IZUMI

				SEMI-CONDUCTOR SINGLE CRYSTAL	
<u>07961182</u>	<u>5462010</u>	250	10/14/1992	APPARATUS FOR SUPPLYING GRANULAR RAW MATERIAL FOR A SEMICONDUCTOR SINGLE CRYSTAL PULLING APPARATUS	FUSEGAWA, IZUMI
<u>07961764</u>	<u>5373805</u>	250	10/15/1992	SINGLE CRYSTAL PULLING APPARATUS	FUSEGAWA, IZUMI
<u>08011744</u>	<u>5340434</u>	250	02/01/1993	PROCESS FOR PRODUCING SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>08012172</u>	<u>5361721</u>	250	02/02/1993	SINGLE CRYSTAL PULLING APPARATUS	FUSEGAWA, IZUMI
<u>08108285</u>	Not Issued	166	08/19/1993	HEAT TREATMENT OF SI SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>08190604</u>	Not Issued	166	02/02/1994	CRUCIBLE FOR PULLING SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>08238722</u>	<u>5534112</u>	150	05/05/1994	METHOD FOR TESTING ELECTRICAL PROPERTIES OF SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>08293214</u>	Not Issued	166	08/19/1994	APPARATUS FOR PRODUCING SILICON SINGLE CRYSTAL GROWN BY CZOCHRALSKI METHOD	FUSEGAWA, IZUMI
<u>08395837</u>	<u>5501172</u>	150	02/28/1995	METHOD OF GROWING SILICON SINGLE CRYSTALS	FUSEGAWA, IZUMI
<u>08445029</u>	Not Issued	166	05/19/1995	HEAT TREATMENT OF SI SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>08510436</u>	<u>5720809</u>	250	08/02/1995	CRUCIBLE FOR PULLING SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>08552164</u>	Not Issued	166	11/02/1995	APPARATUS FOR PRODUCING SILICON SINGLE CRYSTAL GROWN BY CZOCHRALSKI METHOD	FUSEGAWA, IZUMI
<u>08699719</u>	<u>5725661</u>	250	07/01/1996	EQUIPMENT FOR PRODUCING SILICON SINGLE CRYSTALS	FUSEGAWA, IZUMI
<u>08754784</u>	<u>5938841</u>	150	11/21/1996	DEVICE FOR PRODUCING SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>08760959</u>	<u>5766346</u>	150	12/05/1996	APPARATUS FOR PRODUCING SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>08770499</u>	<u>5851283</u>	150	12/20/1996	METHOD AND APPARATUS	FUSEGAWA, IZUMI

				FOR PRODUCTION OF SINGLE CRYSTAL	
<u>08773351</u>	<u>5871583</u>	150	12/26/1996	AN APPARATUS FOR PRODUCING SILICON CRYSTAL	FUSEGAWA, IZUMI
<u>08916291</u>	<u>5834322</u>	250	08/22/1997	HEAT TREATMENT OF SI SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>09270277</u>	<u>6153009</u>	150	03/16/1999	METHOD FOR PRODUCING A SILICON SINGLE CRYSTAL AND THE SILICON SINGLE CRYSTAL PRODUCED THEREBY	FUSEGAWA, IZUMI
<u>09290261</u>	<u>6117231</u>	150	04/13/1999	METHOD OF MANUFACTURING SEMICONDUCTOR SILICON SINGLE CRYSTAL WAFER	FUSEGAWA, IZUMI
<u>09429343</u>	<u>6387466</u>	150	10/28/1999	SINGLE-CRYSTAL SILICON WAFER	FUSEGAWA, IZUMI
<u>09646713</u>	<u>6565822</u>	150	09/21/2000	EPITAXIAL SILICON WAFER, METHOD FOR PRODUCING THE SAME AND SUBSTRATE FOR EPITAXIAL SILICON WAFER	FUSEGAWA, IZUMI
<u>09673480</u>	Not Issued	161	10/16/2000	Method for producing silicon single crystals	FUSEGAWA, IZUMI
<u>09674858</u>	<u>6423285</u>	150	11/07/2000	Method for producing silicon single crystal and production apparatus therefor as well as crystal and silicon wafer produced by the method	FUSEGAWA, IZUMI
<u>09937132</u>	<u>6632280</u>	150	09/21/2001	SINGLE CRYSTAL GROWING DEVICE	FUSEGAWA, IZUMI
<u>09959381</u>	<u>6592662</u>	150	10/24/2001	METHOD FOR PREPARING SILICON SINGLE CRYSTAL AND SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>09979519</u>	<u>6632411</u>	150	11/23/2001	SILICON WAFER AND METHOD FOR PRODUCING SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>10204278</u>	<u>6764548</u>	150	08/20/2002	APPARATUS AND METHOD FOR PRODUCING SILICON SEMICONDUCTOR SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>10204935</u>	<u>6913646</u>	150	08/27/2002	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR PRODUCING SILICON	FUSEGAWA, IZUMI

				SINGLE CRYSTAL	
<u>10312921</u>	6893499	150	12/26/2002	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR MANUFACTURING THE SAME	FUSEGAWA, IZUMI
<u>10500580</u>	Not Issued	93	07/01/2004	AN SOI WAFER AND A METHOD FOR PRODUCING AN SOI WAFER	FUSEGAWA, IZUMI
<u>10510695</u>	Not Issued	41	10/08/2004	METHOD OF MANUFACTURING SILICON SINGLE CRYSTAL, SILICON SINGLE CRYSTAL AND SILICON WAFER	FUSEGAWA, IZUMI
<u>10512470</u>	Not Issued	30	10/26/2004	A SILICON SINGLE CRYSTAL WAFER, AN EPITAXIAL WAFER AND A METHOD FOR PRODUCING A SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>10516347</u>	Not Issued <i>App. 1, cont'd Inventor</i>	30	11/30/2004	GRAPHITE HEATER FOR PRODUCING SINGLE CRYSTAL, APPARATUS FOR PRODUCING SINGLE CRYSTAL, AND METHOD FOR PRODUCING SINGLE CRYSTAL	FUSEGAWA, IZUMI
<u>10538878</u>	Not Issued	41	06/14/2005	Method of producing p-doped silicon single crystal and p-doped n-type silicon single crystal wafer	FUSEGAWA, IZUMI
<u>10542376</u>	Not Issued	30	07/14/2005	AN SOI WAFER AND A METHOD FOR PRODUCING THE SAME	FUSEGAWA, IZUMI
<u>10561865</u>	Not Issued	41	02/20/2006	Method for producing single crystal and single crystal	FUSEGAWA, IZUMI
<u>10568186</u>	Not Issued	20	03/03/2006	Process for producing single crystal and silicon crystal wafer	FUSEGAWA, IZUMI

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Last Name	First Name
Fusegawa	Izumi

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Day : Thursday
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 **PALM INTRANET****Inventor Name Search Result**

Your Search was:

Last Name = SOETA

First Name = SATOSHI

Application#	Patent#	Status	Date Filed	Title	Inventor Name
08759223	5888298	150	12/05/1996	MEMBER-HANDLING MECHANISM, AND MEMBER-HANDLING JIG FOR A CRYSTAL PULLING APPARATUS	SOETA, SATOSHI
08776776	5972106	150	02/10/1997	DEVICE AND METHOD FOR PRODUCING SINGLE CRYSTAL	SOETA, SATOSHI
08804146	5851287	150	02/20/1997	SEED CRYSTAL HOLDER	SOETA, SATOSHI
09508695	6280522	150	03/29/2000	QUARTZ GLASS CRUCIBLE FOR PULLING SILICON SINGLE CRYSTAL AND PRODUCTION PROCESS FOR SUCH CRUCIBLE	SOETA, SATOSHI
10516347	Not Issued <i>App'l. exists' Invention</i>	30	11/30/2004	GRAPHITE HEATER FOR PRODUCING SINGLE CRYSTAL, APPARATUS FOR PRODUCING SINGLE CRYSTAL, AND METHOD FOR PRODUCING SINGLE CRYSTAL	SOETA, SATOSHI

Inventor Search Completed: No Records to Display.

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Inventor Name Search Result

Your Search was:

Last Name = IIDA

First Name = MAKOTO

Application#	Patent#	Status	Date Filed	Title	Inventor Name
<u>05810759</u>	<u>4163215</u>	150	06/28/1977	SAFETY LOCK SYSTEM	IIDA, MAKOTO
<u>05895605</u>	<u>4227577</u>	150	04/12/1978	FIRE-EXTINGUISHING SYSTEM	IIDA, MAKOTO
<u>06336323</u>	<u>4409341</u>	150	12/31/1981	COMPOSITION FOR FIRE RETARDANT URETHANE FOAM	IIDA, MAKOTO
<u>06880012</u>	<u>4734448</u>	150	06/30/1986	PROPYLENE POLYMER COMPOSITION	IIDA, MAKOTO
<u>07219267</u>	Not Issued	166	07/15/1988	ELECTROCONDUCTIVE RESIN COMPOSITION FOR MOLDING AND ELECTROMAGNETIC WAVE INTERFERENCE SHIELD STRUCTURE MOLDED FROM THE COMPOSITION	IIDA, MAKOTO
<u>07538113</u>	<u>5071223</u>	150	06/14/1990	CIRCUIT STRUCTURE FORMED BY INSERT MOLDING OF ELECTRIC AND/OR OPTICAL TRANSMISSION MEDIUM	IIDA, MAKOTO
<u>07592545</u>	Not Issued	166	10/02/1990	FOCUS DRAW-IN METHOD FOR OPTICAL DISC DEVICE	IIDA, MAKOTO
<u>07769348</u>	<u>6156427</u>	250	10/02/1991	ELECTROCONDUCTIVE RESIN COMPOSITION FOR MOLDING AND ELECTROMAGNETIC WAVE INTERFERENCE SHIELD STRUCTURE MOLDED FROM THE COMPOSITION	IIDA, MAKOTO
<u>07785000</u>	<u>5179601</u>	150	10/30/1991	METHOD OF MANUFACTURING CIRCUIT STRUCTURE BY INSERT MOLDING OF ELECTRIC AND/OR OPTICAL TRANSMISSION MEDIUM	IIDA, MAKOTO

<u>07866166</u>	Not Issued	166	06/29/1992	OPTICAL DISK SYSTEM	IIDA, MAKOTO
<u>07939045</u>	Not Issued	166	09/03/1992	FOCUS DRAW-IN SYSTEM FOR OPTICAL DISC DEVICE	IIDA, MAKOTO
<u>08137211</u>	<u>5414682</u>	150	10/18/1993	FOCUS DRAW-IN SYSTEM FOR OPTICAL DISC DEVICE	IIDA, MAKOTO
<u>08172413</u>	<u>5491301</u>	150	12/22/1993	SHIELDING METHOD AND CIRCUIT BOARD EMPLOYING THE SAME	IIDA, MAKOTO
<u>08279318</u>	<u>5461599</u>	150	07/22/1994	OPTICAL DISK SYSTEM	IIDA, MAKOTO
<u>08809295</u>	Not Issued	161	03/27/1997	PROPYLENE RESIN COMPOSITION FOR AUTOMOTIVE INTERIOR PARTS, AND AUTOMOTIVE INTERIOR PARTS	IIDA, MAKOTO
<u>08827060</u>	Not Issued	161	03/26/1997	PRESS WORKING METHOD AND EQUIPMENT THEREFOR	IIDA, MAKOTO
<u>08915397</u>	<u>5871578</u>	150	08/20/1997	METHODS FOR HOLDING AND PULLING SINGLE CRYSTAL	IIDA, MAKOTO
<u>08923963</u>	<u>5911821</u>	150	09/05/1997	METHOD OF HOLDING A MONOCRYSTAL, AND METHOD OF GROWING THE SAME	IIDA, MAKOTO
<u>08929670</u>	<u>5964941</u>	150	09/15/1997	CRYSTAL PULLING METHOD AND APPARATUS	IIDA, MAKOTO
<u>08944869</u>	<u>5882397</u>	150	10/06/1997	CRYSTAL PULLING METHOD	IIDA, MAKOTO
<u>09039830</u>	<u>6053975</u>	150	03/16/1998	CRYSTAL HOLDING APPARATUS	IIDA, MAKOTO
<u>09101941</u>	<u>6120749</u>	150	07/17/1998	SILICON SINGLE CRYSTAL WITH NO CRYSTAL DEFECT IN PERIPHERAL PART OF WAFER AND PROCESS FOR PRODUCING THE SAME	IIDA, MAKOTO
<u>09109530</u>	<u>5968264</u>	150	07/02/1998	METHOD AND APPARATUS FOR MANUFACTURING A SILICON SINGLE CRYSTAL HAVING FEW CRYSTAL DEFECTS, AND A SILICON SINGLE CRYSTAL AND SILICON WAFERS MANUFACTURED BY THE SAME	IIDA, MAKOTO
<u>09140288</u>	<u>5948164</u>	250	08/25/1998	SEED CRYSTAL HOLDER	IIDA, MAKOTO

<u>09173931</u>	<u>6027562</u>	150	10/16/1998	METHOD FOR PRODUCING A SILICON SINGLE CRYSTAL HAVING FEW CRYSTAL DEFECTS, AND A SILICON SINGLE CRYSTAL AND SILICON WAFERS PRODUCED BY THE METHOD	IIDA, MAKOTO
<u>09188490</u>	<u>6066306</u>	150	11/09/1998	SILICON SINGLE CRYSTAL WAFER HAVING FEW CRYSTAL DEFECTS, AND METHOD FOR PRODUCING THE SAME	IIDA, MAKOTO
<u>09194232</u>	<u>6445872</u>	150	11/23/1998	RECORDING AND REPRODUCING APPARATUS FOR RECORDING DIGITAL BROADCAST COMPRESSION-CODED DATA T OF VIDEO SIGNALS OF A MULTIPLICITY OF CHANNELS	IIDA, MAKOTO
<u>09197130</u>	<u>6048395</u>	150	11/20/1998	METHOD FOR PRODUCING A SILICON SINGLE CRYSTAL HAVING FEW CRYSTAL DEFECTS	IIDA, MAKOTO
<u>09264514</u>	<u>6191009</u>	150	03/08/1999	METHOD FOR PRODUCING SILICON SINGLE CRYSTAL WAFER AND SILICON SINGLE CRYSTAL WAFER	IIDA, MAKOTO
<u>09294323</u>	<u>6191675</u>	150	04/20/1999	HIGH VOLTAGE TRANSFORMER AND IGNITION TRANSFORMER USING THE SAME	IIDA, MAKOTO
<u>09313856</u>	<u>6299982</u>	150	05/18/1999	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR PRODUCING SILICON SINGLE CRYSTAL WAFER	IIDA, MAKOTO
<u>09318055</u>	<u>6077343</u>	150	05/25/1999	SILICON SINGLE CRYSTAL WAFER HAVING FEW DEFECTS WHEREIN NITROGEN IS DOPED AND A METHOD FOR PRODUCING IT	IIDA, MAKOTO
<u>09329615</u>	<u>6197109</u>	150	06/10/1999	METHOD FOR PRODUCING LOW DEFECT SILICON SINGLE CRYSTAL DOPED WITH NITROGEN	IIDA, MAKOTO
<u>09359078</u>	<u>6159438</u>	150	07/22/1999	METHOD AND APPARATUS FOR MANUFACTURING A	IIDA, MAKOTO

				SILICON SINGLE CRYSTAL HAVING FEW CRYSTAL DEFECTS, AND A SILICON SINGLE CRYSTAL AND SILICON WAFERS MANUFACTURED BY THE SAME	
<u>09454841</u>	<u>6120599</u>	150	12/06/1999	SILICON SINGLE CRYSTAL WAFER HAVING FEW CRYSTAL DEFECTS, AND METHOD FOR PRODUCING THE SAME	IIDA, MAKOTO
<u>09459849</u>	<u>6120598</u>	150	12/13/1999	METHOD FOR PRODUCING A SILICON SINGLE CRYSTAL HAVING FEW CRYSTAL DEFECTS, AND A SILICON SINGLE CRYSTAL AND SILICON WAFERS PRODUCED BY THE METHOD	IIDA, MAKOTO
<u>09492001</u>	<u>6348180</u>	150	01/26/2000	SILICON SINGLE CRYSTAL WAFER HAVING FEW CRYSTAL DEFECTS	IIDA, MAKOTO
<u>09572788</u>	<u>6780067</u>	150	05/17/2000	COMBINED INTEGRAL MOLDED PRODUCT USING PRE-MOLDED MEMBER	IIDA, MAKOTO
<u>09577252</u>	<u>6261361</u>	150	05/19/2000	Silicon single crystal wafer having few defects wherein nitrogen is doped and a method for producing it	IIDA, MAKOTO
<u>09600033</u>	<u>6334896</u>	150	07/11/2000	SINGLE-CRYSTAL SILICON WAFER HAVING FEW CRYSTAL DEFECTS AND METHOD FOR MANUFACTURING THE SAME	IIDA, MAKOTO
<u>09661985</u>	<u>6364947</u>	150	09/14/2000	Method and apparatus for manufacturing a silicon single crystal Having few crystal defects, and a silicon single crystal and silicon wafers manufactured by the same	IIDA, MAKOTO
<u>09828206</u>	<u>6401643</u>	250	04/09/2001	SEWN COVER ASSEMBLY AND PRODUCT FOAMED THEREWITH	IIDA, MAKOTO
<u>09830386</u>	<u>6544332</u>	150	04/26/2001	METHOD FOR MANUFACTURING SILICON SINGLE CRYSTAL, SILICON SINGLE CRYSTAL	IIDA, MAKOTO

				MANUFACTURED BY THE METHOD, AND SILICON WAFER	
<u>09868058</u>	<u>6548035</u>	150	06/14/2001	SILICON SINGLE CRYSTAL WAFER FOR EPITAXIAL WAFER, EPITAXIAL WAFER, AND METHODS FOR PRODUCING THE SAME AND EVALUATING THE SAME	IIDA, MAKOTO
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<u>10009910</u>	Not Issued	123	12/12/2001	Silicon wafer, silicon epitaxial wafer, anneal wafer and method for producing them	IIDA, MAKOTO
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